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Is a Transition metal-Silicon Quadruple Bond Viable?

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Computational Details

Geometry optimization has been performed using M06-2X,¹ M11² and PBE³ levels of density functional theory using def2-TZVP basis set. Harmonic vibrational frequency calculations were also performed at the same level of theory to understand the nature of stationary point. All these structures were found to be at their local minimum geometry. Single point multi-configurational complete-active-space-self-consistent-field (CASSCF) calculations were further performed on the M11 optimized geometries to verify the electronic configurations. The calculations used 12 electrons in 12 orbitals, i.e., CASSCF(12e,12o) for closed shell singlet and CASSCF(11e,12o) for the doublet ground state geometries of H₃Si-Ru(CO)₃ and HSi=Ru(CO)₃ molecules. All these calculations were performed using GAUSSIAN16 suite of program.⁴ The relaxed force constant calculations were performed using Compliance3.0.2 program.^{5,6} Adaptive natural density partitioning (AdNDP)⁷ analyses were performed using Multiwfn⁸ on the M11 optimized geometries.

References

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Fig S1. Relative energies (kcal/mol) of the isomers in their singlet and triplet states calculated at M11/def2-TZVP level.



Fig S2. AdNDP orbitals showing 5c-2e bonds with their corresponding occupation number (ON).

Cartesian coordinates of the optimized geometries at different DFT functionals, lowest vibrational frequency along with the total energy in a.u.

SiRu(CO)₃, C_{3V}, ¹A₁ (M06-2X/def2-TZVP)

 $v1 = 27.5 \text{ cm}^{-1}$

Sum of electronic and zero-point Energies=				-724.294981		
Sum of electronic and thermal Energies=				-724.284756		
Sun	ı of electronic ar	-724.283812				
Sun	Sum of electronic and thermal Free Energies= -724.334660					
44	0.000398000	0.000156000	-0.183401	000		
6	0.848982000	-1.740312000	-0.3729780	000		
6	1.094802000	1.597787000	-0.3731010	00		
6	-1.929941000	0.140779000	-0.3820560	000		
8	1.344718000	-2.757222000	-0.4647780	000		
8	1.734289000	2.530906000	-0.4659610	00		
8	-3.057249000	0.222950000	-0.4868880	000		
14	-0.019617000	0.002180000	1.869961	000		

SiRu(CO)₃, *C*_{3V}, ¹A₁ (M11/def2-TZVP)

 $v1 = 58.5 \text{ cm}^{-1}$

Sum of electronic and zero-point Energies= Sum of electronic and thermal Energies=				-724.291081 -724.281413	
Sun	n of electronic an	nd thermal Free	Energies=	-724.328540	
44	0.000208000	0.000009000	-0.174863	000	

•••	0.000200000	0.00000000000	0.17 1002 000	
6	-0.615754000	1.829494000	-0.375203000	
6	-1.276011000	-1.448242000	-0.375626000	
6	1.892734000	-0.381046000	-0.374449000	

8	-0.976060000	2.898443000	-0.492508000
8	-2.021775000	-2.294579000	-0.493055000
8	2.998610000	-0.603694000	-0.491430000
14	-0.001511000	-0.000213000	1.875828000

SiRu(CO)₃, C_{3V}, ¹A₁ (PBE/def2-TZVP)

 $v1 = 47.4 \text{ cm}^{-1}$

Sum of electronic and zero-point Energies= Sum of electronic and thermal Energies=				-724.068994 -724.059192	
Sur	n of electronic ar	nd thermal Free	Energies=	-724.107077	
44	-0.000354000	-0.000007000	-0.164987	000	
6	-0.861332000	1.714806000	-0.3885890	000	
6	-1.062400000	-1.598047000	-0.3892970	000	
6	1.914177000	-0.115364000	-0.3963790	000	
8	-1.369966000	2.727736000	-0.5160630	000	
8	-1.689860000	-2.541894000	-0.5175390	000	
8	3.044690000	-0.183412000	-0.5322450	000	
14	0.013857000	-0.001964000	1.916556	000	